DBB PACKAGE

(TOP VIEW)

- **Member of the Texas Instruments** Widebus™ Family
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- Bus Hold on Data Inputs Eliminates the **Need for External Pullup/Pulldown** Resistors
- Plastic 300-mil Thin Shrink Small-Outline **Package**

description

This 1-bit to 2-bit address driver is designed for 1.65-V to 3.6-V V_{CC} operation.

Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

To ensure the high-impedance state during power up or power down, the output-enable (OE) input should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74ALVCH16830 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE

	INPUTS	OUT	OUTPUTS		
OE1	OE2 A		1Yn	2Yn	
L	Н	Н	Н	Z	
L	Н	L	L	Z	
Н	L	Н	Z	Н	
Н	L	L	Z	L	
L	L	Н	Н	Н	
L	L	L	L	L	
Н	Н	Χ	z	Z	

(TOP VIEW)								
2Y2	Н	1	U	80	h	1Y3		
1Y2	П	2		79		2Y3		
GND	d	3		78		GND		
2Y1	d	4		77	6	1Y4		
1Y1	d	5		76	6	2Y4		
V_{CC}	d	6		75	þ	V_{CC}		
A1	Ц	7		74	þ	1Y5		
A2	П	8		73		2Y5		
GND	Ц	9		72	0	GND		
A3	Ц	10		71	0	1Y6		
A4	Ц	11		70	0	2Y6		
GND	Ц	12		69	Į	GND		
A5	Ц	13		68	Ų	1Y7		
A6	Ц	14		67	2	2Y7		
Vcc	Ц	15		66	P	VCC		
A7	Ц	16		65	Ľ	1Y8		
A8	Н	17		64	K	2Y8		
GND	Н	18		63	K	GND		
A9	Н	19		62	K	1Y9		
OE1	Н	20		61	K	2Y9		
OE2 A10	H	21		60	K	1Y10		
GND	H	22		59	K	2Y10		
A11	H	23		58 57	R	GND 1Y11		
A11	H	24		57 50	K	2Y11		
V _{CC}	H	25 26		56 55	K	V _{CC}		
A13	H	27		55 54	K	1Y12		
A14	H	28		53	K	2Y12		
GND	H	29		52	K	GND		
A15	K	30		51	K	1Y13		
A16	H	31		50	K	2Y13		
GND	H	32		49	K	GND		
A17	ď	33		48	Ħ	1Y14		
A18	П	34		47	ħ	2Y14		
V_{CC}	d	35		46	ħ	V_{CC}		
2Y18	d	36		45	6	1Y15		
1Y18	d	37		44	6	2Y15		
GND	d	38		43		GND		
2Y17		39		42	þ	1Y16		
1Y17		40		41	þ	2Y16		
					-			

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

–0.5 V to V_{CC} + 0.5 V
–50 mA
–50 mA
±50 mA
±100 mA
106°C/W
–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 4.6 V maximum.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

			MIN	MAX	UNIT	
VCC	Supply voltage		1.65	3.6	V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
٧ıH	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	СС	
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8		
٧ _I	Input voltage		0	Vcc	V	
٧o	Output voltage		0	VCC	V	
		V _{CC} = 1.65 V		-4	mA	
1	High-level output current	V _{CC} = 2.3 V		-12		
IOH		V _{CC} = 2.7 V		-12		
		V _{CC} = 3 V		-24		
		V _{CC} = 1.65 V		4		
la.	Low-level output current	V _{CC} = 2.3 V	12 12		mA	
lOL		V _{CC} = 2.7 V				
		V _{CC} = 3 V		24		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CO	ONDITIONS	vcc	MIN	TYP†	MAX	UNIT
		I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} -0.	.2		
	I _{OH} = -4 mA		1.65 V	1.2				
		I _{OH} = -6 mA		2.3 V	2			
Vон				2.3 V	1.7			V
		$I_{OH} = -12 \text{ mA}$		2.7 V	2.2			
				3 V	2.4			
		I _{OH} = -24 mA		3 V	2			
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2	
		I _{OL} = 4 mA		1.65 V			0.45	
\/a:		I _{OL} = 6 mA		2.3 V			0.4	1/
VOL		lo 12 mΔ	2.3 V			0.7	V	
		I _{OL} = 12 mA	2.7 V			0.4		
		I _{OL} = 24 mA	3 V			0.55		
lį		V _I = V _{CC} or GND		3.6 V			±5	μΑ
		V _I = 0.58 V	1.65 V	25				
		V _I = 1.07 V	1.65 V	-25			μΑ	
		V _I = 0.7 V	2.3 V	45				
I _I (hold)		V _I = 1.7 V	2.3 V	-45				
		V _I = 0.8 V		3 V	75			
		V _I = 2 V	3 V	-75				
		$V_{I} = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$	3.6 V			±500		
loz		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ
Icc		$V_I = V_{CC}$ or GND,	I _O = 0	3.6 V			40	μΑ
∆lcc		One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μΑ
	Control inputs	VI = Voc or GND		3.3 V				n.E
Ci	Data inputs	V _I = V _{CC} or GND						pF
Co	Outputs	$V_O = V_{CC}$ or GND		3.3 V				pF

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 2.7 V	V _{CC} = 3.3 V ± 0.3 V	UNIT
		(001701)	TYP	MIN MAX	MIN MAX	MIN MAX	
t _{pd}	А	Y					ns
t _{en}	ŌĒ	Υ					ns
^t dis	ŌĒ	Y					ns

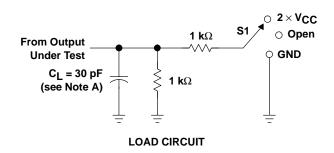
[‡] This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

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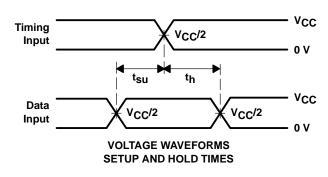
operating characteristics, T_A = 25°C

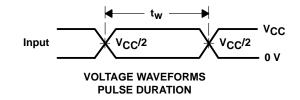
PARAMETER		TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	UNIT	
C _{pd}	Power dissipation	Outputs enabled	C _L = 0, f = 10 MH	7			ρF
Фра	capacitance	Outputs disabled	0L = 0, 1 = 10 mm				۲۱

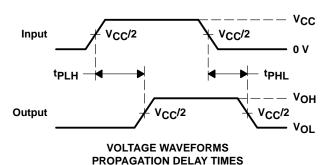
PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V}$

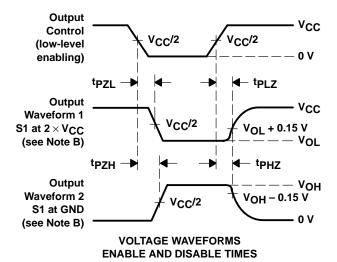












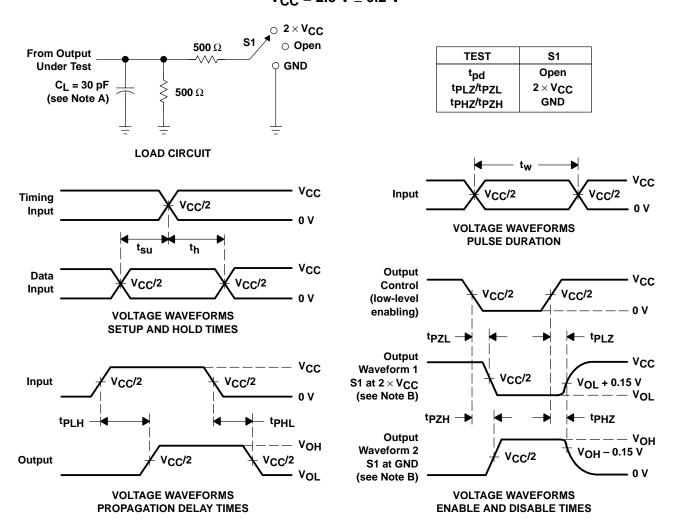
NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpZL and tpZH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.5 V \pm 0.2 V



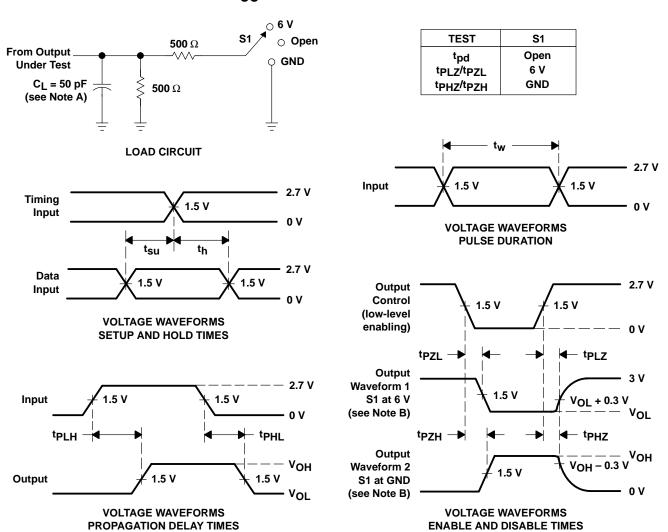
- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpLH and tpHL are the same as tpd.

Figure 2. Load Circuit and Voltage Waveforms



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PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_r \leq 2.5 \,\text{ns}$, $t_f \leq 2.5 \,\text{ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. tpLz and tpHz are the same as tdis.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. tpLH and tpHL are the same as tpd.

Figure 3. Load Circuit and Voltage Waveforms